

Negative Fixed 12V Voltage Regulator in bare die form

Rev 1.0 19/04/19

Description

The 7912 12V fixed 3-terminal negative voltage regulator delivers up to 1.5A of output current with adequate heat-sinking. The device is equipped with internal limiting, safe-area compensation + thermal shutdown features for overload immunity. The 7912 can be used with external components to obtain adjustable voltages or currents & can also be used as the power-pass element in precision high-current voltage regulators. No external components are needed other than to enhance performance or increase design flexibility.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection
 + MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
 + MIL-PRF-38534 Class K (AT)

LAT = Lot Acceptance Test.

For further information on LAT places flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

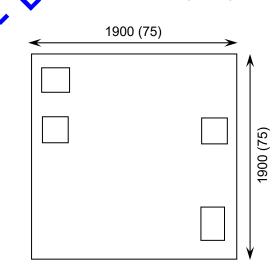
Supply Formats:

- Defaut Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Tape & Reel On request
- In Metal or Ceramic package On request

Features:

- ±5% V_{OUT} tolerance over entire temperature range
- Greater than 1A output current capability
- Internal thermal overload processing
- Internal short-circuit current imit
- Output capacitor not essential for stability
- Full military te npenature range
- Positive voltage complement is 7812

Die Qimensions in µm (mils)



Mechanical Specification

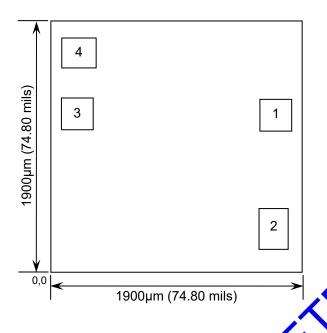
Die Size (Unsawn)	1900 x1900 75 x 75	μm mils	
Minimum Bond Pad Size	230 x 230 9.05 x 9.05	µm mils	
Die Thickness	280 (±20) 11.02 (±0.79)	μm mils	
Top Metal Composition	Al 1%Si 1.1µm		
Back Metal Composition	Ti/Ni/Ag 1.2 μm		





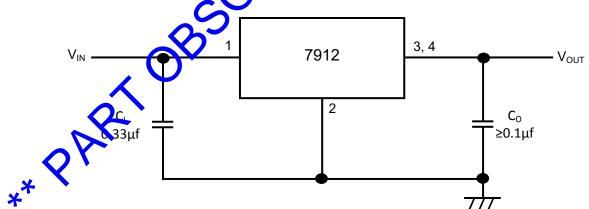
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Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)			
TAD TONCTION	X	Y			
1	V _{IN}	1.575	1.074		
2	GNV	1.572	0.188		
3	V _{OU}	0.088	1.059		
4	V _{OUT}	0.088	1.553		
CONNECT CHIP BACK TO VIV					

Typical Application



 C_l is required if the regulator is located an appreciable distance from power supply filter. C_0 is not required for stability; however it does improve transient response. For optimum stability and transient response locate C_l C_0 as close as possible to the regulator. A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.





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Absolute Maximum Ratings

PARAMETER	SYMBOL	VALUE	UNYI		
Input Voltage	V _{IN}	-35	//		
Power Dissipation ¹	P _D	Internally Limited	V		
Operating Temperature Range	-	-55 to 150	°C		
Maximum Junction Temperature	T _J	150	°C		
Storage Temperature	T _{STG}	-65 to 150	°C		

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V _{IN}		-25	V
Output Current	I _{OUT}	9	1.5	A
Operating Temperature Range	T _J	-55	125	°C

DC Electrical Characteristics, V_I =-19V, I_{OUT}=50mA, C_I=0.33μF, C_O=0.1μf, T_{MIN}≤T_J≤T_{MAX}(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Output Voltage	V _{OUT}	T _J = 25°C	-11.50	-12	-12.50		
		5m/ ≤ l ₀ - ≤ 1A, -14.5V ≥ / _{IN} ≥ -27V, P _D ≤ 15 Watts	-11.40	-	-12.60	V	
Line Regulation	ΔV _{OUT}	-14.5V≥ViN =-39V,I _{OUT} =0.1A,T _J =25°C	-	13	120	mV	
		-16V≥V _N ≥>22V,I _{OUT} =0.1A,T _J = 25°C	-	6	60		
Line Regulation		-1 <mark>4.5V₃V_{IN}≥-30V,I_{OUT}=0.5A,T_J=25°C</mark>	-	55	240		
		$J_{\text{IN}} \ge V_{\text{IN}} \ge -22V, I_{\text{OUT}} = 0.5A, T_{\text{J}} = 25^{\circ}\text{C}$	-	24	120		
Load Regulation	ΔV _{Ου} τ	$5\text{mA} \le I_{\text{OUT}} \le 1.5\text{A}, T_{\text{J}} = 25^{\circ}\text{C}$	-	46	240		
		250mA ≤ I _{OUT} ≤ 750mA, T _J = 25°C	-	17	120		
Input Bias Current		T _J = 25°C	-	4.3	7.8	mA	
Input Bias Current 🗸	Input Bias Current ΔI_B	-14.5V ≥ V _{IN} ≥ -27V	-	-	1.0	mA	
Change	ΔIB	5mA ≤ I _{OUT} ≤ 1.5A	-	-	0.5	ША	
Output Noice Voltage	V _n	10Hz ≤ f ≤ 100KHz, T _J = 25°C	-	75	-	µV/V _{OUT}	
Ripple Rejection	RR	I _{OUT} = 20mA, f = 120Hz,	-	61	-	dB	
Dropout Voltage	$V_{IN} - V_{OUT}$	I _{OUT} = 1A, T _J = 25°C	-	2	-	V	
Peak Output Current	I _{MAX}	T _J = 25°C	-	2.1	-	А	
Avg. Output Voltage Temp. Coefficient	TCV _{OUT}	$I_{OUT} = 5\text{mA}, \ 0^{\circ}\text{C} \le T_{J} \le +125^{\circ}\text{C}$	-	-1.0	-	mV/°C	

^{1.} Results in die form are dependent on die attach and assembly method. Max power dissipation is internally limited by the die.





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Typical Characteristics

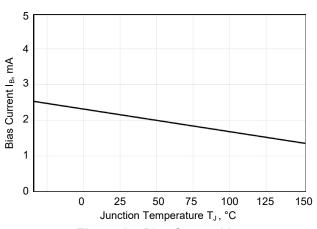


Figure 1 – Bias Current Versus Temperature

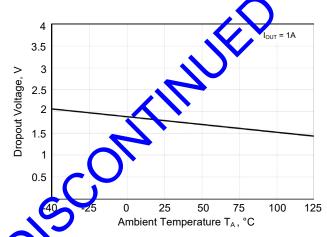


Figure 2 – Dropout Voltage Versus Temperature

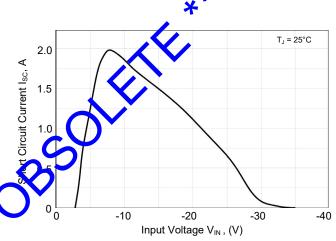


Figure 3 – Short-Circuit Current Versus Input Voltage

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